

Transistors

2SC9016

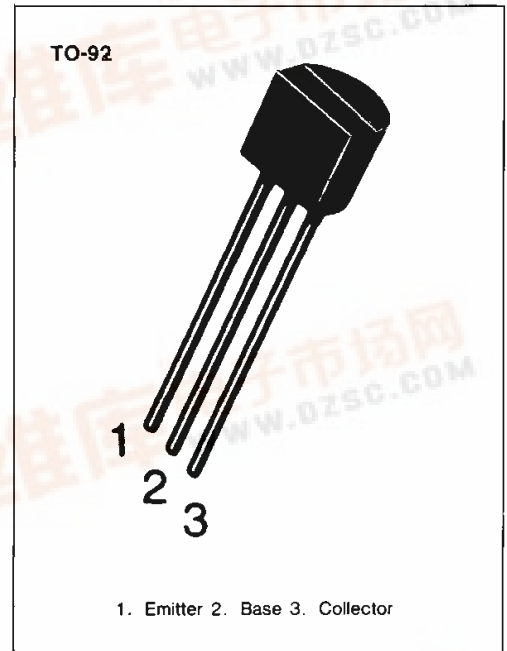


AM CONVERTER, FM/RF AMPLIFIER OF LOW NOISE.

- High total power dissipation. (PT=400mW)

ABSOLUTE MAXIMUM RATINGS (T_a = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V _{CB0}	30	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EBO}	4	V
Collector Current	I _C	25	mA
Collector Dissipation	P _C	400	mW
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55~150	°C

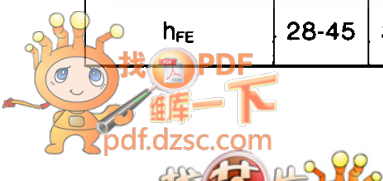


ELECTRICAL CHARACTERISTICS (T_a = 25°C)

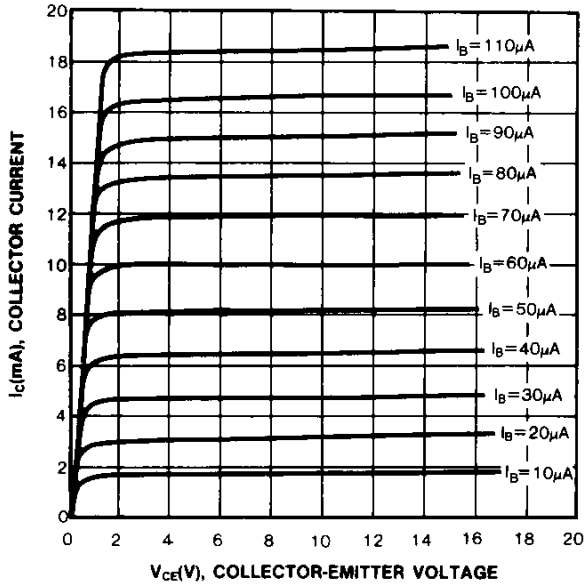
Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	BV _{CB0}	I _C = 100μA, I _E = 0	30			V
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C = 1mA, I _B = 0	20			V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E = 100μA, I _C = 0	4			V
Collector Cutoff Current	I _{CB0}	V _{CB} = 30V, I _E = 0			100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} = 3V, I _C = 0			100	nA
DC Current Gain	h _{FE}	V _{CE} = 5V, I _C = 1mA	28	90	198	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C = 10mA, I _B = 1mA		0.1	0.3	V
Base-Emitter On Voltage	V _{BE (on)}	V _{CE} = 5V, I _C = 1mA		0.72		V
Output Capacitance	C _{ob}	V _{CB} = 10V, I _E = 0 f = 1MHz		1.2	1.6	pF
Current Gain-Bandwidth Product	f _T	V _{CE} = 5V, I _C = 1mA	400	620		MHz
Noise Figure	NF	V _{CE} = 5V, I _C = 1.0mA f = 100MHz, R _s = 50Ω		3.0	5.0	dB

h_{FE} CLASSIFICATION

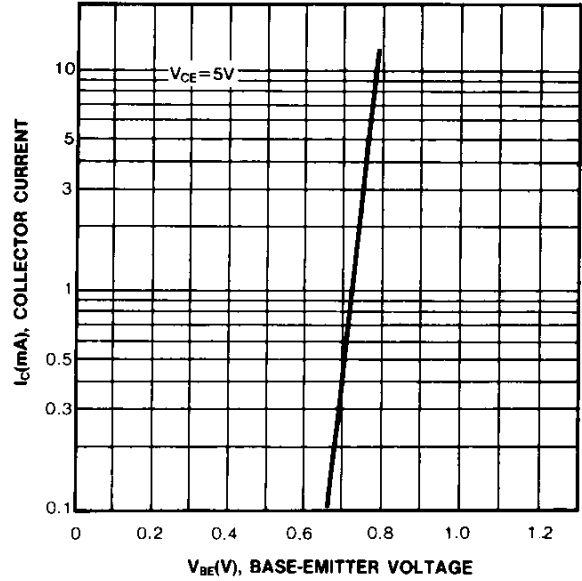
Classification	D	E	F	G	H	I
h _{FE}	28-45	39-60	54-80	72-108	97-146	132-198



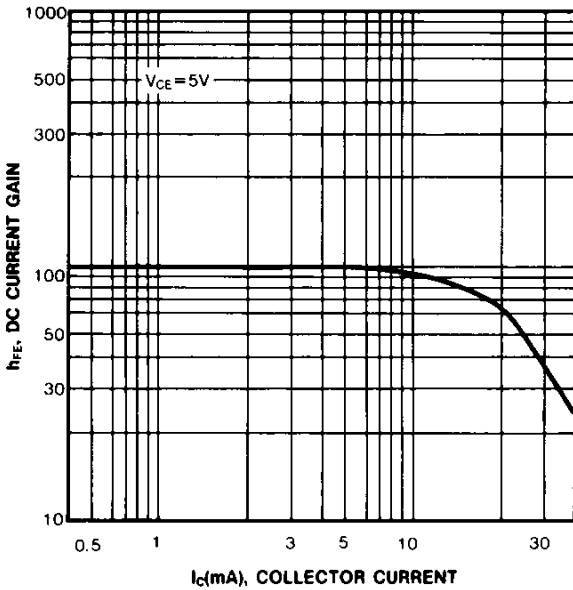
STATIC CHARACTERISTIC



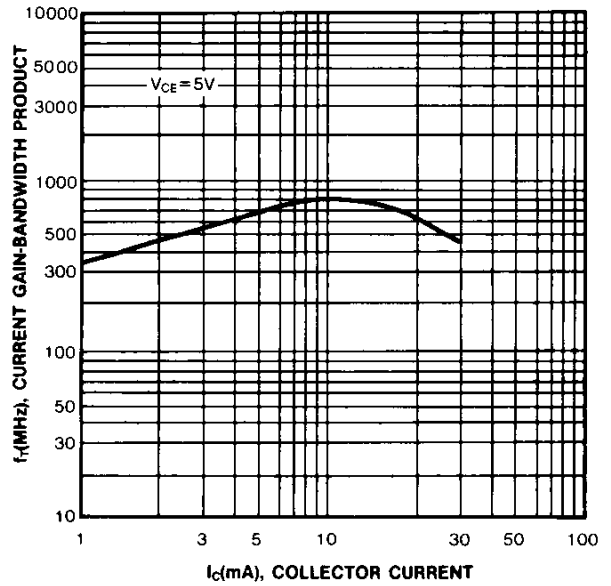
BASE-EMITTER ON VOLTAGE



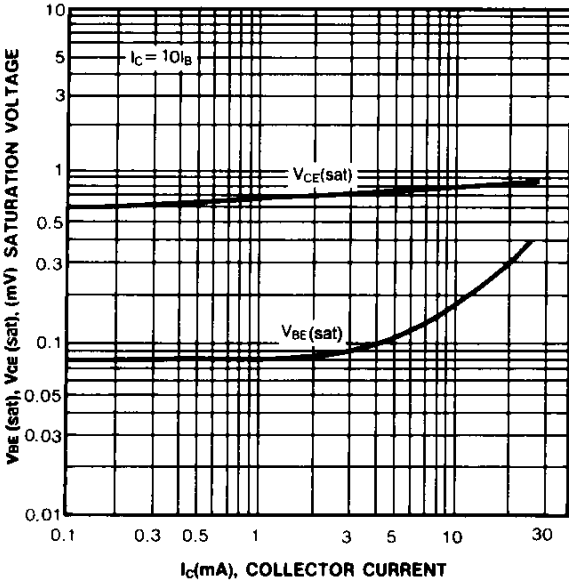
DC CURRENT GAIN



CURRENT GAIN-BANDWIDTH PRODUCT



**BASE-EMITTER SATURATION VOLTAGE
COLLECTOR-EMITTER SATURATION VOLTAGE**



COLLECTOR OUTPUT CAPACITANCE

